

2SC4708

Silicon NPN Epitaxial  
High Resolution Monitor Video Output

Feature

- Excellent high frequency characteristics  
 $f_T = 1.1 \text{ GHz typ}$   
 $C_{ob} = 4.2 \text{ pF typ}$
- High gain bandwidth product
- Low collector output capacitance
- High breakdown voltage  
 $V_{CEO} = 100 \text{ V}$

Absolute Maximum Ratings (Ta = 25°C)

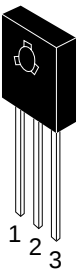
| Item                         | Symbol        | Rating      | Unit |
|------------------------------|---------------|-------------|------|
| Collector to base voltage    | $V_{CBO}$     | 100         | V    |
| Collector to emitter voltage | $V_{CEO}$     | 100         | V    |
| Emitter to base voltage      | $V_{EBO}$     | 3           | V    |
| Collector current            | $I_C$         | 0.2         | A    |
| Collector peak current       | $i_{C(peak)}$ | 0.5         | A    |
| Collector power dissipation  | $P_C$         | 1           | W    |
|                              | $P_C^{*1}$    | 5           | W    |
| Junction temperature         | $T_j$         | 150         | °C   |
| Storage temperature          | $T_{stg}$     | -55 to +150 | °C   |

Note: 1. Value at  $T_C = 25^\circ\text{C}$ .

Electrical Characteristics (Ta = 25°C)

| Item                                   | Symbol        | Min | Typ | Max | Unit          | Test condition                               |
|----------------------------------------|---------------|-----|-----|-----|---------------|----------------------------------------------|
| Collector to base breakdown voltage    | $V_{(BR)CBO}$ | 100 | —   | —   | V             | $I_C = 10 \mu\text{A}, I_E = 0$              |
| Collector to emitter breakdown voltage | $V_{(BR)CEO}$ | 100 | —   | —   | V             | $I_C = 1 \text{ mA}, R_{BE} = \infty$        |
| Collector cutoff current               | $I_{CBO}$     | —   | —   | 1.0 | $\mu\text{A}$ | $V_{CB} = 80 \text{ V}, I_E = 0$             |
| Emitter cutoff Current                 | $I_{EBO}$     | —   | —   | 10  | $\mu\text{A}$ | $V_{EB} = 3 \text{ V}, I_C = 0$              |
| DC current transfer ratio              | $h_{FE}^{*1}$ | 60  | —   | 200 |               | $V_{CE} = 10 \text{ V}, I_C = 10 \text{ mA}$ |

TO-126 MOD



- 1. Emitter
- 2. Collector
- 3. Base

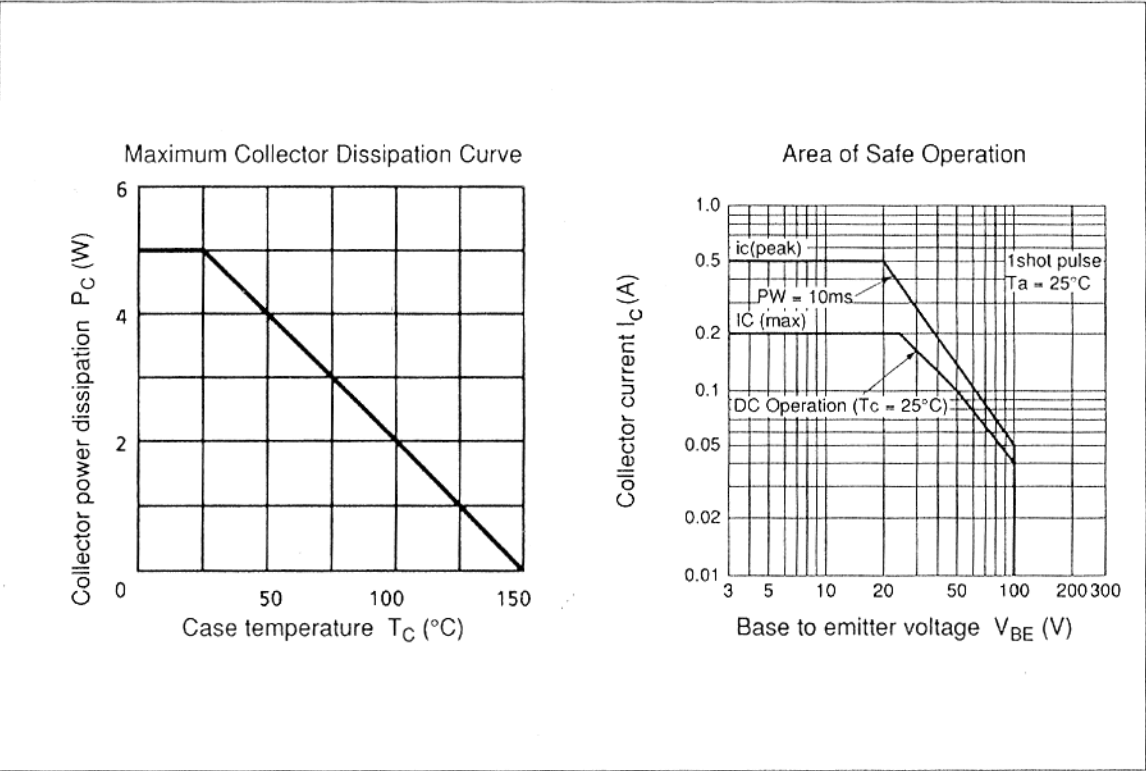
2SC4708

Electrical Characteristics (Ta = 25°C) (cont)

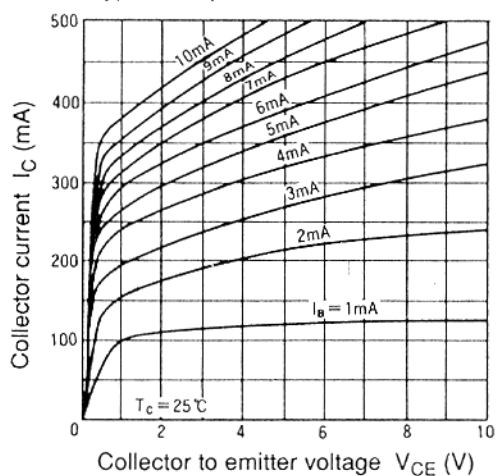
| Item                                    | Symbol        | Min | Typ  | Max | Unit | Test condition                                    |
|-----------------------------------------|---------------|-----|------|-----|------|---------------------------------------------------|
| Base to emitter voltage                 | $V_{BE}$      | —   | —    | 1.0 | V    | $V_{CE} = 10\text{ V}, I_C = 10\text{ mA}$        |
| Collector to emitter saturation voltage | $V_{CE(sat)}$ | —   | —    | 1.0 | V    | $I_C = 100\text{ mA}, I_B = 10\text{ mA}$         |
| Gain bandwidth product                  | $f_T$         | 800 | 1100 | —   | MHz  | $V_{CE} = 10\text{ V}, I_C = 100\text{ mA}$       |
| Collector output capacitance            | $C_{ob}$      | —   | 4.2  | 6.0 | pF   | $V_{CB} = 30\text{ V}, I_E = 0, f = 1\text{ MHz}$ |

Note: 1. The 2SC4708 is grouped by  $h_{FE}$ , and its specification is as follows.

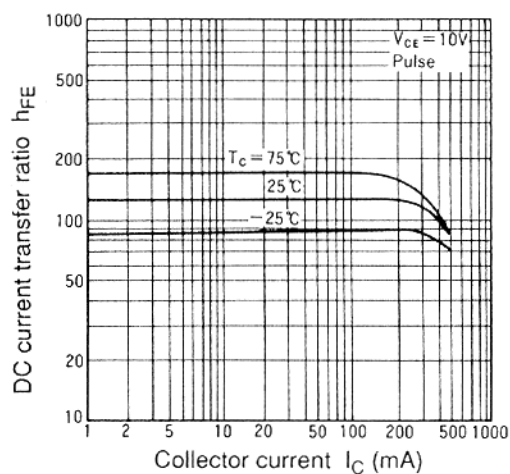
|           |            |
|-----------|------------|
| B         | C          |
| 60 to 120 | 100 to 200 |



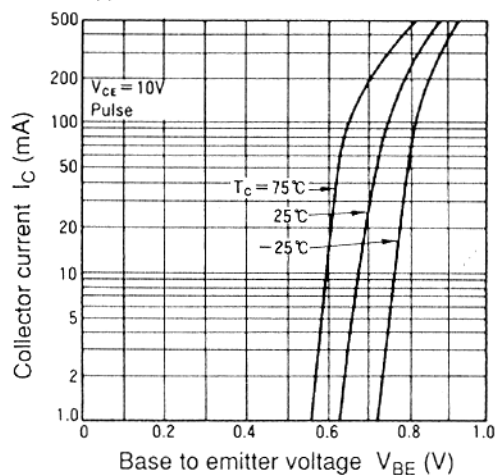
Typical Output Characteristics



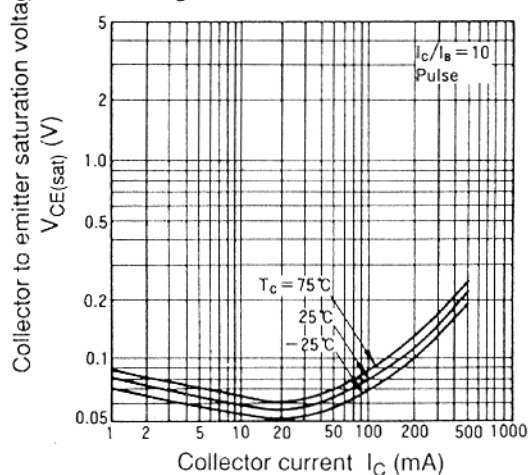
DC Current Transfer Ratio vs. Collector Current



Typical Transfer Characteristics



Collector to Emitter Saturation Voltage vs. Collector Current



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